

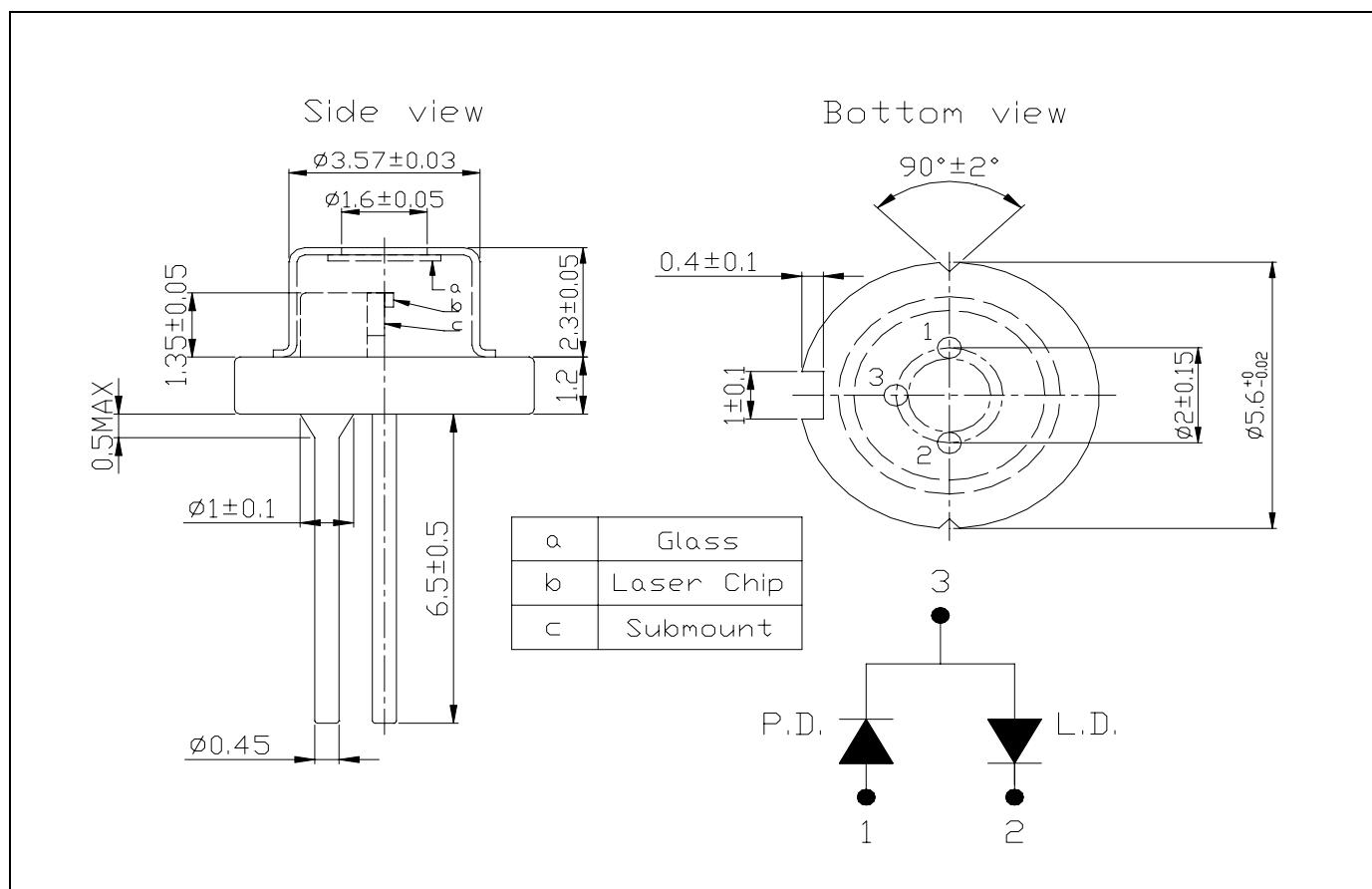
650nm Red Laser Diode

RLD65000503

(1) Device: Laser Diode

(2) Structure: TO-18(ϕ 5.6mm), With Pb free glass cap, PD

■ External dimensions(Unit : mm)



■ Absolute Maximum Ratings($T_c=25^\circ C$)

Parameter		Symbol	Value	Unit
Optical Output		Po	5	mW
Reverse Voltage	Laser	Vr	2	V
	PIN PD	Vr(PIN)	30	V
Operating Temperature		Top	-10~+40	°C
Storage Temperature		Tstg	-15~+85	°C

■ Electrical and Optical Characteristics($T_c=25^{\circ}\text{C}$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit	
Threshold Current	I_{th}	$P_o=5\text{mW}$	-	12	25	mA	
Operating Current	I_{op}	$P_o=5\text{mW}$	-	18	25	mA	
Operating Voltage	V_{op}	-	-	2.1	2.5	Volt	
Slope Efficiency	η	4mW-1mW	0.4	0.8	-	mW/mA	
		$I_{4\text{mW}}-I_{1\text{mW}}$					
Monitor Current	I_m	$P_o=5\text{mW}$	0.05	0.3	0.5	mA	
Beam Divergence (FWHM)	Parallel	$\theta //$	$P_o=5\text{mW}$	5	9	12	deg.
	Perpendicular	$\theta \perp$	$P_o=5\text{mW}$	30	36	42	deg.
Lasing Wavelength	λ	$P_o=5\text{mW}$	640	655	660	nm	

◎ $\theta //$ and $\theta \perp$ are defined as the angle within which the intensity is 50% of the peak value.

■ Typical characteristic curves

